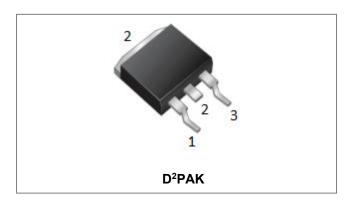


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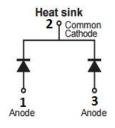
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SDURB1660CT ULTRAFAST RECTIFIER



Circuit Diagram



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Features

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- "-A" is an AEC-Q101 qualified device
- Terminals finish: 100% Pure Tin
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	600	V
Average Rectified Forward Current (Per Device)	IF (AV)	50% duty cycle @Tc=100°C, rectangular wave form	8(Per Leg) 16(Per Device)	A
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	80	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V_{F1}	@ 8A, Pulse, T _J = 25°C	1.3	2.2	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R,} T_J = 25^{\circ}C$	0.3	5	μA
	I _{R2}	$@V_R = rated V_R, T_J = 125^{\circ}C$	84	500	μA
Reverse Recovery Time(Per Leg)	t _{rr}	I_F =500mA, I_R =1A,and I_m =250mA	46	50	ns

* Pulse width < 300 μ s, duty cycle < 2%

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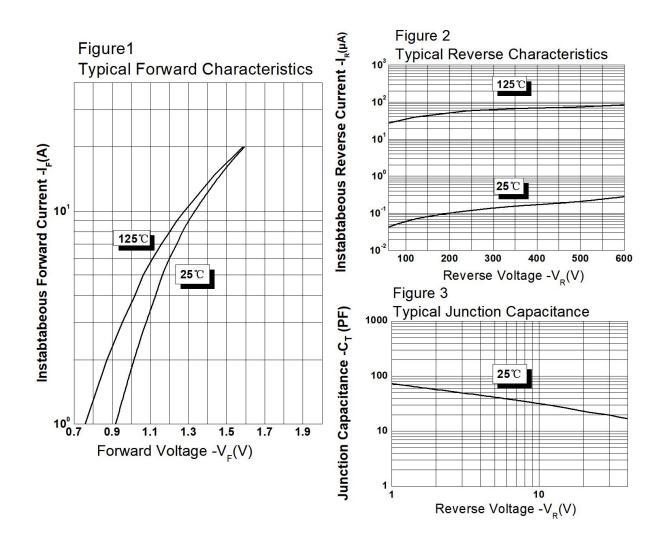
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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	5	°C/W
Approximate Weight	wt	-	1.85	g
Case Style		D ² PAK		

Ratings and Characteristics Curves





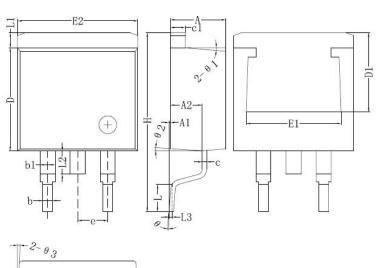
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Mechanical Dimensions D²PAK



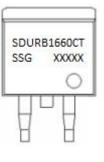
Symbol	Dimensions in millimeters		
,	Min.	Max.	
A	4.06	4.83	
A1	0	0.26	
b	0.51	0.99	
b1	1.14	1.78	
с	0.31	0.74	
c1	1.14	1.65	
D	8.38	8.65	
D1	6.86		
E1	6.22		
E2	9.65	10.67	
е	2.54BSC		
Н	14.60	15.88	
L	1.78	2.80	
L1	-	1.68	
L2	-	1.78	
L3	0.255BSC		
Θ	0	8°	

Ordering Information

Device	Package	Shipping
SDURB1660CT	D ² PAK	800pcs / reel
SDURB1660CTTR	D ² PAK	800pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

SDUR = Device Type

в

16

60

СТ

YΥ

Т

ŴŴ

SSG

- = Package type
- = Forward Current (16A) = Reverse Voltage(600V)

= Configuration

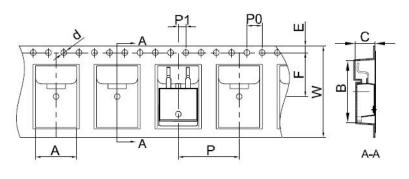
= SSG

= Year

= Week = Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Carrier Tape Specification D²PAK



SYMBOL	Millimeters		
STIVIDUL	Min.	Max.	
А	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
E	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

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